4.5 Ω High Bandwidth, Dual **SPDT Analog Switch**

The NLAS4717 is an advanced CMOS analog switch fabricated in sub-micron silicon gate CMOS technology. The device is a dual independent Single Pole Double Throw (SPDT) switch featuring two low $R_{DS(on)}$ of 4.5 Ω at 3.0 V.

The device also features guaranteed Break-Before-Make (BBM) switching, assuring the switches never short the driver.

- The NLAS4717 is available in two small size packages:
- ◆ Micro10: 3.0 x 5.0 mm
- ♦ Flip-Chip-10: 2.0 x 1.5 mm

Features

- Low R_{DS(on)}: 4.5 Ω @ 3.0 V
- Matching Between the Switches $\pm 0.5 \Omega$
- Wide Low Voltage Range: 1.8 V to 5.5 V
- High Bandwidth > 40 MHz
- 1.65 V to 5.5 V Operating Range
- Low Threshold Voltages on Pins 4 and 8 (CTRL Pins)
- Ultra-Low Charge Injection $\leq 6.0 \text{ pC}$
- SNOT RECONTACT • Low Standby Current – $I_{CC} = 1.0 \text{ nA} (Max) @ T_A = 25^{\circ}C$
- OVT* on Pins 4 and 8 (CTRL Logic Pins)
- Pb-Free Packages are Available

Typical Applications

- Cell Phones
- PDAs
- MP3s
- Digital Still Cameras

Important Information

- ESD Protection:
 - HBM = 2000 V, MM = 200 V
- Latchup Max Rating: 200 mA (Per JEDEC EIA/JESD78)
- Pin-to-Pin Compatible with MAX4717

*OVT

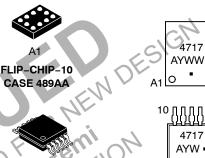
• Overvoltage Tolerance (OVT) specific pins to operate higher than normal supply voltages, with no damage to the devices or to signal integrity.



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MARKING DIAGRAMS



= Assembly Location

= Year

Micro10

CASE 846B

- W, WW = Work Week
 - = Pb-Free Package

FUNCTION TABLE

IN_	NO_	NC_
0	OFF	ON
1	ON	OFF

ORDERING INFORMATION

Device	Package	Shipping [†]
NLAS4717FCT1	Flip-Chip-10	3000 / Tape & Reel
NLAS4717FCT1G	Flip-Chip-10 (Pb-Free)	3000 / Tape & Reel
NLAS4717MR2	Micro10	4000 / Tape & Reel
NLAS4717MR2G	Micro10 (Pb-Free)	4000 / Tape & Reel

+For information on tape and reel specifications. including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ENTATIVEFOR

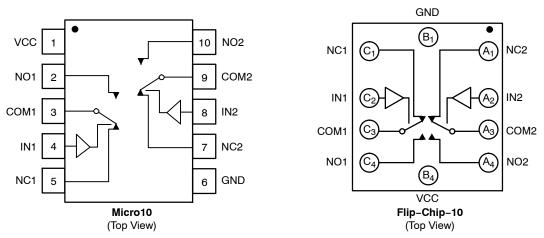


Figure 1. Device Circuit Diagrams and Pin Configurations

-1

MAXIMUM RATINGS

Symbol	Parameter Value	Unit
V+	Positive DC Supply Voltage -0.5 to +7.0	V
V _{IS}	Analog Input Voltage (V _{NO} , V _{NC} , or V _{COM}) (Note 1) $-0.5 \le V_{IS} \le V_{CC} + 0.5$	V
V _{IN}	Digital Select Input Voltage $-0.5 \le V_{I} \le +7.0$	V
Ι _{ΙΚ}	DC Current, Into or Out of Any Pin (Continuous) ±100	mA
I _{PK}	Peak Current (10% Duty Cycle) ±200	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Signal voltage on NC, NO, and COM exceeding VCC or GND are clamped by the internal diodes. Limit forward diode current to maximum current rating.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Мах	Unit
V+	DC Supply Voltage	1.8	5.5	V
V _{IN}	Digital Select Input Voltage	GND	5.5	V
V _{IS}	Analog Input Voltage (NC, NO, COM)	GND	V _{CC}	V
T _A	Operating Temperature Range	-40	+85	°C
t _r , t _f	Input Rise or Fall Time, SELECT $ \begin{array}{c} V_{CC} = 3.3 \ V \ \pm \ 0.3 \ V \\ V_{CC} = 5.0 \ V \ \pm \ 0.5 \ V \end{array} $	0 0	100 20	ns/V

ANALOG SWITCH DC CHARACTERISTICS

	6			-40°C t	o +85°C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Мах	Unit
V _{IH}	Input Logic High Voltage	V _{OUT} = 0.1 V I _{OUT} ≤ 20 μA	1.65 to 2.2 2.7 to 3.6 4.5 to 5.5	V _{CC} x 0.55 V _{CC} x 0.5 2.0		V
V _{IL}	Input Logic Low Voltage	$V_{OUT} = -V_{CC} - 0.1 \text{ V}$ $I_{OUT} \le 20 \mu\text{A}$	1.65 to 2.2 2.7 to 3.6 4.5 to 5.5	- - -	V _{CC} x 0.2 V _{CC} x 0.2 0.8	V
I _{IN}	Input Leakage Current	$V_{IN} - V_{CC}$ or GND	5.0	-100	+100	nA
V _{CC}	Power Supply Range	All	-	1.65	5.5	V
I _{CC}	Supply Current	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0 \ \mu A$	1.8 3.3 5.0	- - -	1.0 1.0 1.0	μΑ
V _{IS}	Analog Signal Range	Key parameter	-	0	V _{CC}	V

ANALOG SWITCH CHARACTERISTICS - Digital Section (Voltages Referenced to GND)

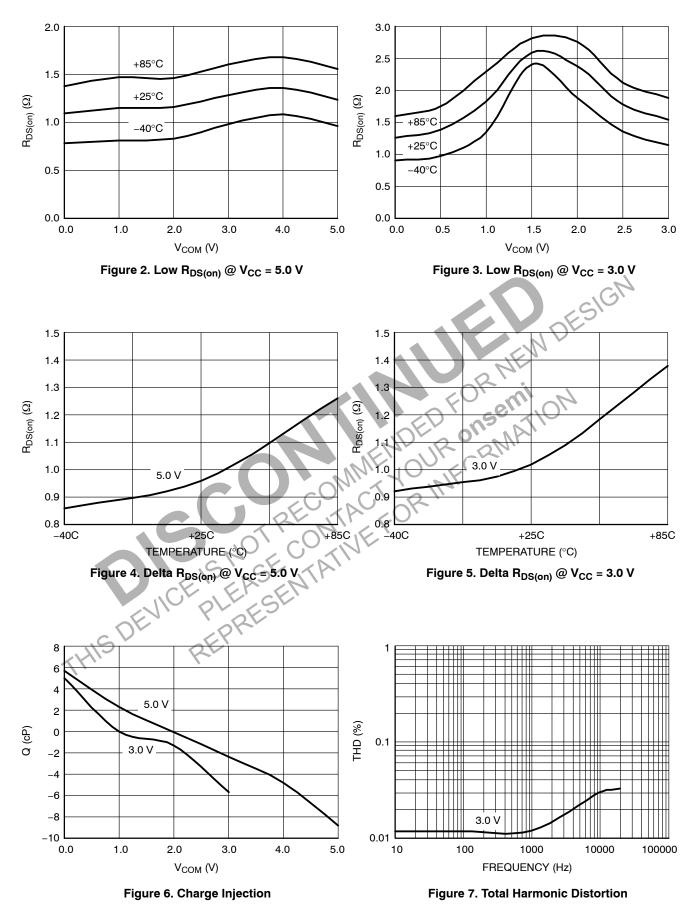
				-	40°C to +85°	C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
R _{ON}	ON Resistance (Note 2)	$V_{CC} = 3.0 \text{ V}$ $I_{COM} = 10 \text{ mA}$ $V_{NO} \text{ or } V_{NC} = V_{IH} \text{ or } V_{IL}$	3.0	-		4.5	Ω
		$V_{CC} = 5.0 \text{ V}$ $I_{COM} = 10 \text{ mA}$ $V_{NO} \text{ or } V_{NC} = V_{IH} \text{ or } V_{IL}$	5.0	-		3.5	
ΔR _{ON}	ON Resistance Match Between Channels (Note 2 and 3)	$V_{CC} = 3.6 \text{ V}$ $I_{COM} = 10 \text{ mA}$ $V_{NO} \text{ or } V_{NC} = V_{IH} \text{ or } V_{IL}$	3.6	-	0.1	0.4	Ω
		$V_{CC} = 5.5 \text{ V}$ $I_{COM} = 10 \text{ mA}$ $V_{NO} \text{ or } V_{NC} = V_{IH} \text{ or } V_{IL}$	5.5			GN	
R _{FLAT[ON]}	ON Resistance Flatness (Note 4)	$I_{COM} = 10 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	3.0		NDE	5 1.5	Ω
		$I_{COM} = 10 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	5.5	RN		1.36	
I _{NO_[OFF]} I _{NC_[OFF]}	NO_, NC_ Off-Leakage Current (Note 5)	$V_{CC} = 3.6 \text{ V} \\ V_{COM} = 0.3 \text{ V or } 3.3 \text{ V} \\ V_{NO} \text{ or } V_{NC} = 0.3 \text{ V or } 3.3 \text{ V} \\ \end{array}$	3.6 ED	Onsen	0.01	+1.0	nA
		$V_{CC} = 5.5 \text{ V}$ $V_{COM} = 0 \text{ V or } 5.0 \text{ V}$ $V_{NO} \text{ or } V_{NC} = 0 \text{ V or } 5.0 \text{ V}$	10, N	FORM	0.01	+1.0	
ICOM ^[ON]	COM_ On-Leakage Current (Note 5)	$V_{CC} = 3.6 V$ $V_{COM} = 0.3 V \text{ or } 3.3 V$ $V_{NO} \text{ or } V_{NC} = 0.3 V \text{ or } 3.3 V$	F03.6	-2.0	0.01	+2.0	nA
	DICEIS	$V_{CC} = 5.5 V$ $V_{COM} = 0 V \text{ or } 5.0 V$ $V_{NO} \text{ or } V_{NC} = 0 V \text{ or } 5.0 V$	5.5	-2.0	0.01	+2.0	

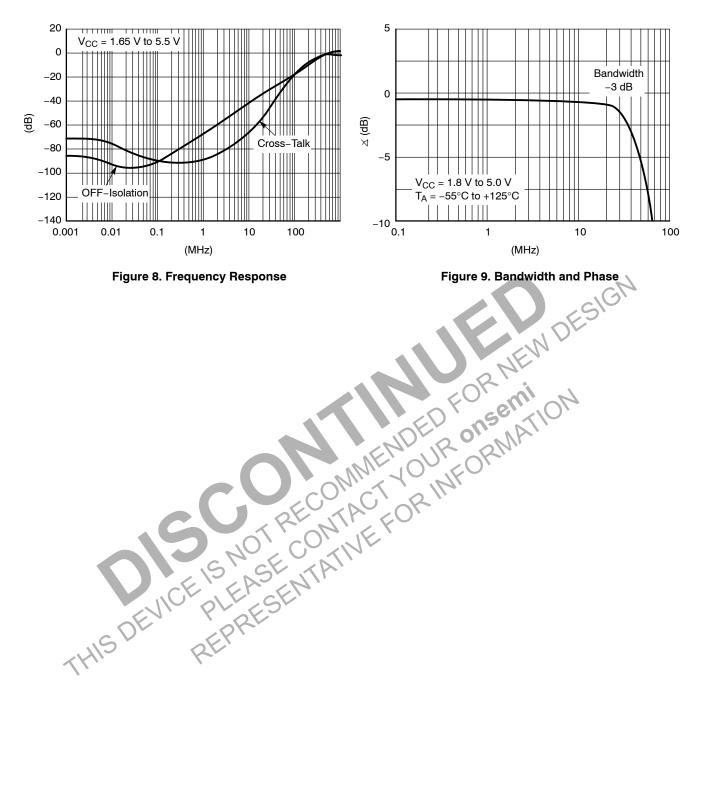
ANALOG SWITCH AC CHARACTERISTICS

	IS RE			-	40°C to +85°	C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
t _{ON}	Turn-On Time	$ \begin{array}{l} V_{NC_}, V_{NO_} = V_{IH} \text{ or } V_{IL} \\ R_{L} = 300 \; \Omega, C_{L} = 35 \; pF \\ V_{IN[x]} = V_{IH} \; or \; V_{IL} \end{array} $	1.8 to 5.5	-	-	30	nS
toff	Turn-Off Time	$ \begin{array}{l} V_{\text{NC}_}, V_{\text{NO}_} = V_{\text{IH}} \text{ or } V_{\text{IL}} \\ R_{\text{L}} = 300 \ \Omega, \ C_{\text{L}} = 35 \ pF \\ V_{\text{IN}[x]} = V_{\text{IH}} \text{ or } V_{\text{IL}} \end{array} $	1.8 to 5.5	-	-	40	nS
^t ввм	Break-Before-Make Time Delay (Note 5)	$V_{NC_{-}}, V_{NO_{-}} = 1.5 V$ $R_{L} = 300 \Omega, C_{L} = 35 pF$	_	-	8.0	-	nS
t _{SKEW}	Skew (Note 5)	R_S = 39 Ω , C_L = 50 pF	-	_	0.15	2.0	nS

2. R_{ON} characterized for V_{CC} range (1.65 V to 5.5 V). 3. $\Delta R_{ON} = R_{ON}(MAX) - R_{ON}(MIN)$. 4. $R_{FLAT[ON]} = R_{ON}(MAX) - R_{ON}(MIN)$, measured over V_{CC} range. 5. Guaranteed by design.

				-	40°C to +85°	С	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
Q	Charge Injection	V _{IN} = V _{CC} to GND	3.0		6.0		рС
		R_{ln} = 0 Ω , C_L = 1.0 nF	5.0		9.0		
		$Q = C_L - \Delta V_{OUT}$					
VISO	Off-Isolation	f = 10 MHz	1.65 to 5.5		-50		dB
		V _{NO_} , V _{NC_} = 1.0 Vp-p					
		$R_L = 50 \Omega$, $C_L = 5.0 pF$					
		f = 1.0 MHz			-75		
		V _{NO} _, V _{NC} _ = 1.0 Vp-p					
		R_L = 50 Ω , C_L = 5.0 pF					
VCT	Cross-Talk	f = 10 MHz	1.65 to 5.5		-80		dB
		V _{NO} _, V _{NC} _ = 1.0 Vp–p					
		$R_L = 50 \Omega$, $C_L = 5.0 pF$				40	
		f = 1.0 MHz			-110	S	
		V _{NO} _, V _{NC} _ = 1.0 Vp-p					
		R_L = 50 Ω , C_L = 5.0 pF			NV		
BW	On-Channel	Signal = 0 dB	1.8 to 5.0		40		MHz
	-3.0 db Bandwidth	$R_L = 50 \ \Omega, \ C_L = 5.0 \ pF$		2	~ *		
THD	Total Harmonic Distortion	V _{COM} = 2.0 Vp–p, RL = 600 Ω, T _A <i>=</i> 25°C		FUiger	0.02		%
C _{NO_[OFF]}	NO_, NC_	F = 10 MHz	GEE	0	30		pF
C _{NC_[OFF]}	OFF-Capacitance			- 2N			
C _{NO_[ON]} C _{NC_[ON]}	NO_, NC_ ON-Capacitance	F = 10 MHz	×10, r	FO'	110		pF
	DEVICE PL	F= 10 MHz ONNE NOT REOTATION FASENTATION FRESENTATION	FOR				





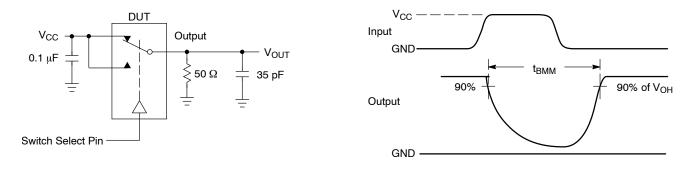
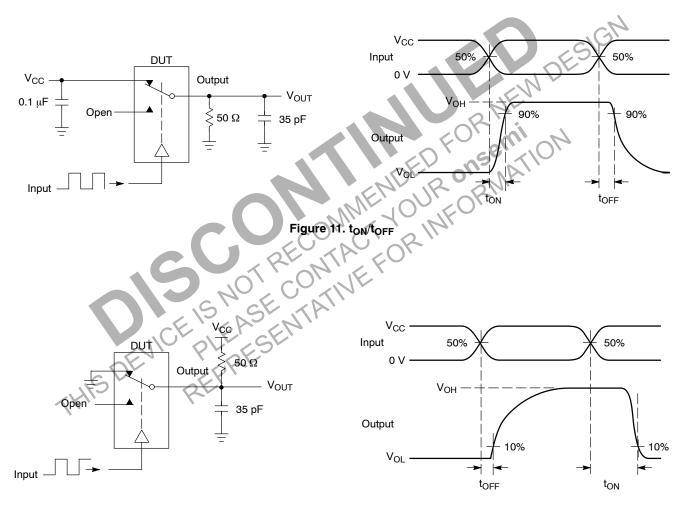
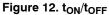
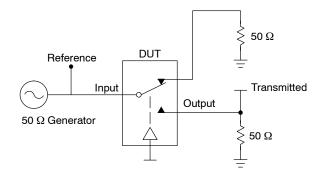


Figure 10. t_{BBM} (Time Break-Before-Make)



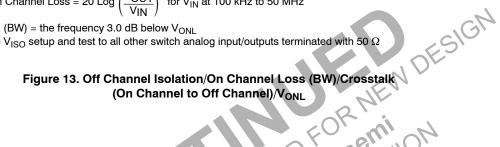


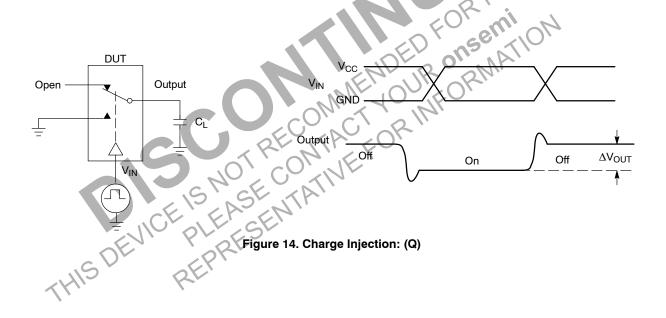


Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. VISO, Bandwidth and VONL are independent of the input signal direction.

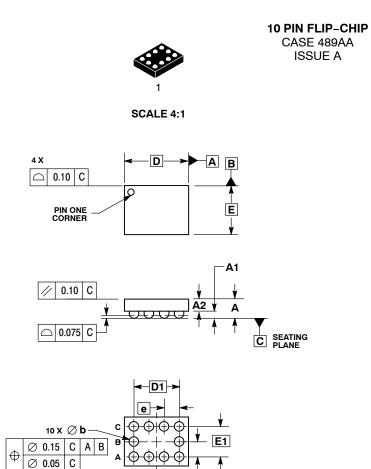
 $V_{ISO} = Off Channel Isolation = 20 Log \left(\frac{V_{OUT}}{V_{IN}} \right)$ for V_{IN} at 100 kHz V_{ONL} = On Channel Loss = 20 Log $\left(\frac{V_{OUT}}{V_{IN}}\right)$ for V_{IN} at 100 kHz to 50 MHz

Bandwidth (BW) = the frequency 3.0 dB below V_{ONL} V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω





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DATE 04 MAY 2004

NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION:

- MILLIMETERS. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS. З.

	MILLIN	IETERS	
DIM	MIN	MAX	
Α		0.650	
A1	0.210	0.270	
A2	0.280	0.380	
D	1.965	BSC	
E	1.465	BSC	
b	0.250	0.350	
е	0.500 BSC		
D1	1.500 BSC		
E1	1.000	BSC	

GENERIC **MARKING DIAGRAM***

A1	xxxx YYWW O	
=	Specific D	evi

XXXX	= Specific Device Code
YY	= Year
WW	= Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " .", may or may not be present.

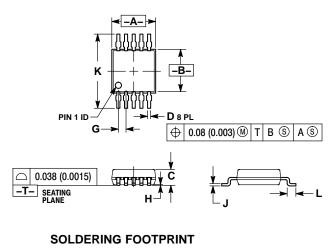
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SCALE 2:1



10x $\frac{1.04}{0.041}$ 0.32 10X 0.0126 3.20 4.24 5.28 0.126 0.167 0.208 0.50 8x 0.0196 mm SCALE 8:1 (inches)

Micro10

Micro10 CASE 846B **ISSUE D**

DATE 07 DEC 2004

- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION "B" DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 5. 846B-01 OBSOLETE. NEW STANDARD 846B-02

	MILLIN	IETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
С	0.95	1.10	0.037	0.043
D	0.20	0.30	0.008	0.012
G	0.50 BSC		0.020 BSC	
Н	0.05	0.15	0.002	0.006
J	0.10	0.21	0.004	0.008
К	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

GENERIC **MARKING DIAGRAM***

I	00000
	XXXX AYW
I	00000

- хххх = Device Code
 - = Assembly Location
 - = Year

A Y

W

•

- = Work Week
- = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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